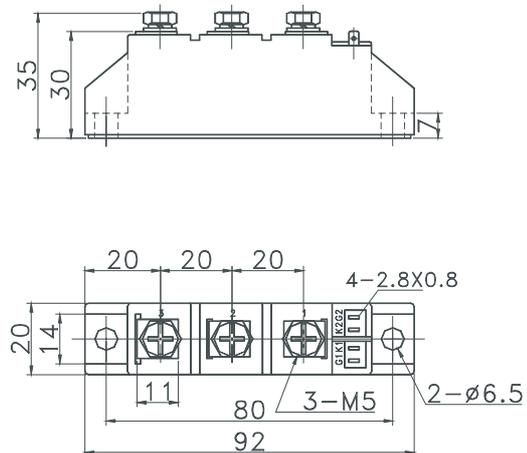
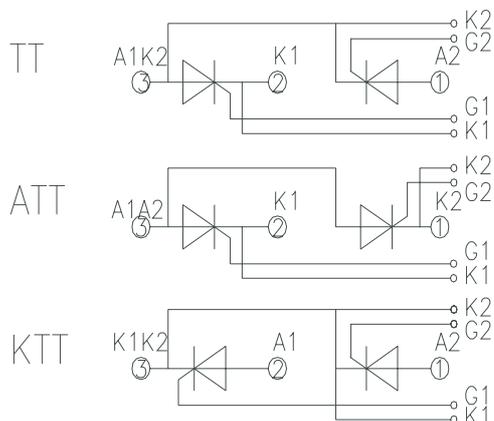


TT26 ATT26 KTT26

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT	
				Min	Type	Max		
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _c =85°C	125			26	A	
I _{T(RMS)}	RMS on-state current	as AC switch				56	A	
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V _{DRM} &V _{RRM} tp=10ms V _{DsM} &V _{RsM} = V _{DRM} &V _{RRM} +200V respectively	125	600		1800	V	
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			8	mA	
I _{TSM}	Surge on-state current	10ms half sine wave	125			0.55	KA	
I ² t	I ² T for fusing coordination	V _R =60%V _{RRM}					1.50	A ² s*10 ³
V _{TO}	Threshold voltage	125				0.85	V	
r _T	On-state slop resistance						9.68	m
V _{TM}	Peak on-state voltage	I _{TM} =78A 125				1.69	V	
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM} 125				800	V/ s	
di/dt	Critical rate of rise of on-state current	From 67%V _{DRM} to 78A, Gate source 1.5A t _r "0.5 s Repetitive	125			50	A/ s	
I _{GT}	Gate trigger current	V _A =12V, I _A =1A 25		30		100	mA	
V _{GT}	Gate trigger voltage				0.8		2.0	V
I _H	Holding current				20		100	mA
V _{GD}	Non-trigger gate voltage	At 67%V _{DRM} 125				0.2	V	
R _{th(j-c)}	Thermal resistance Junction to heatsink	At 180° sine' Single side cooled				0.950	°C /W	
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} :1mA(MAX)		2500			V	
F _m	Thermal connection torque(M5)					0.20	Nm	
	Mounting torque(M6)					0.30	Nm	
T _{stg}	Stored temperature			-40		140	°C	
W _t	Weight					100	g	
Outline	201F3							

OUTLINE DRAWING & CIRCUIT DIAGRAM


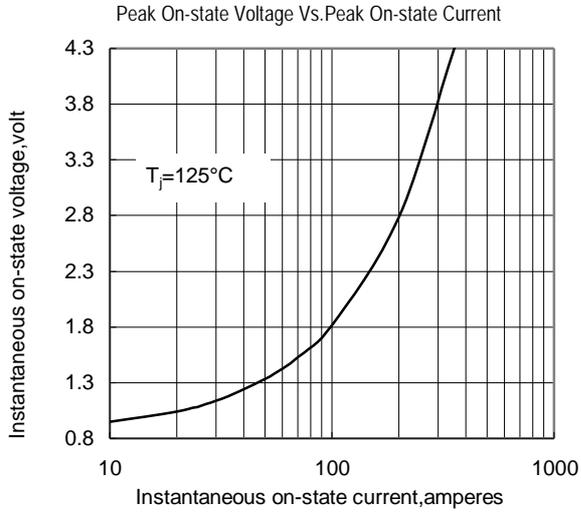


Fig.1

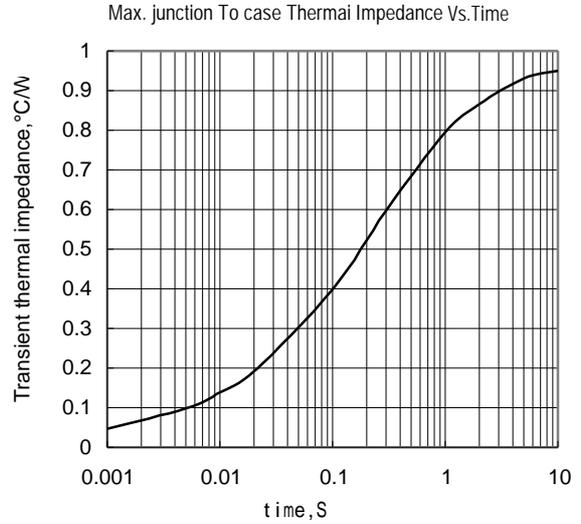


Fig.2

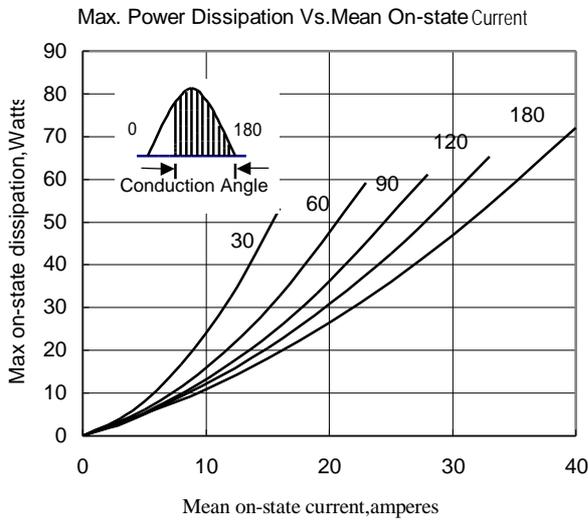


Fig.3

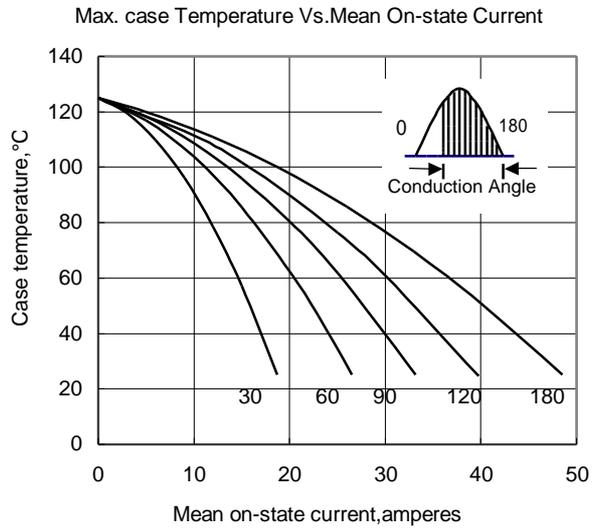


Fig.4

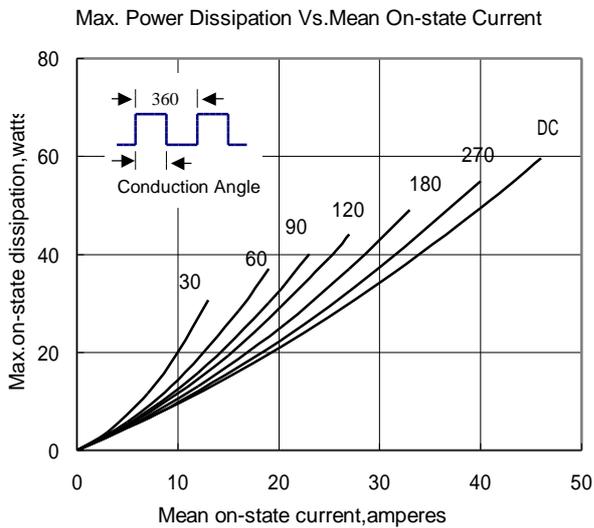


Fig.5

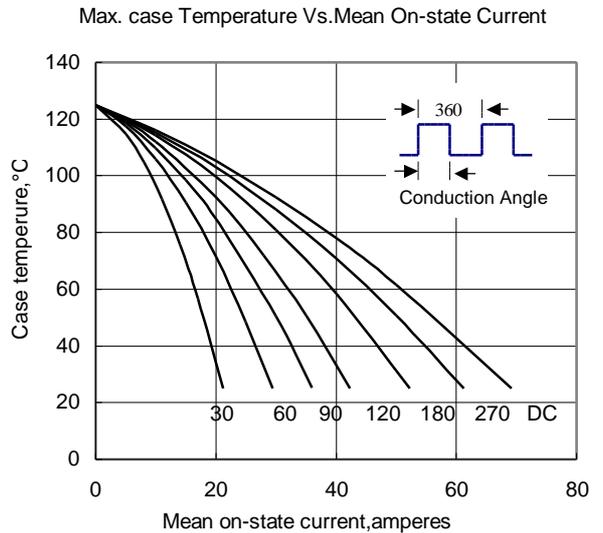


Fig.6

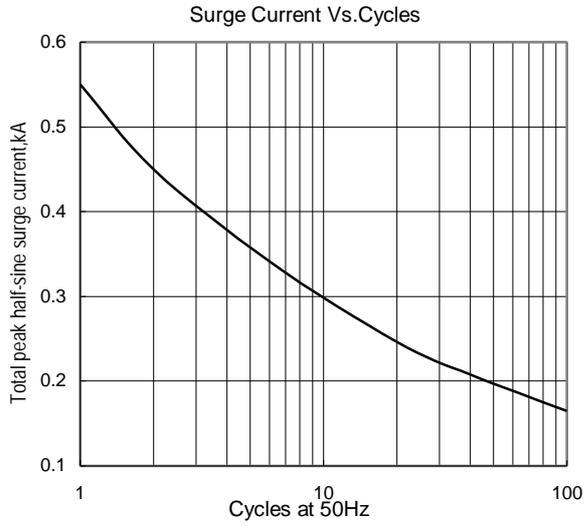


Fig.7

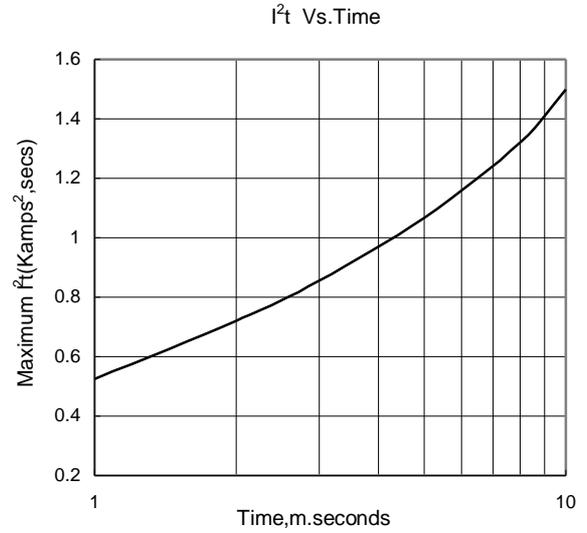


Fig.8

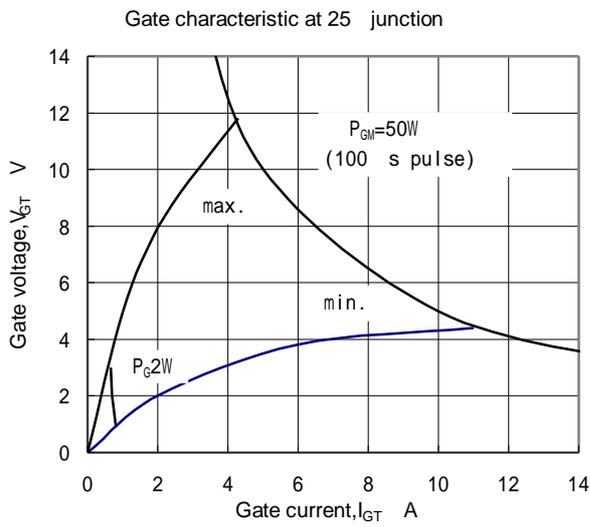


Fig.9

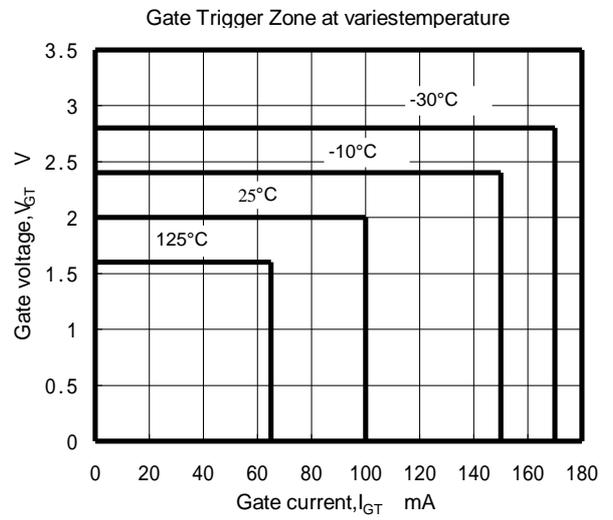


Fig.10